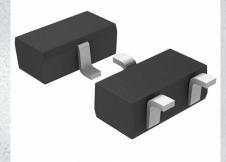


UNR31AEGOL Datasheet

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UNR31AEGOL-DG
Panasonic Electronic Components
UNR31AEGOL
TRANS PREBIAS PNP 50V SSSMINI3
Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biase d 50 V 80 mA 80 MHz 100 mW Surface Mount SSSM ini3-F2

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
UNR31AEG0L	Panasonic Electronic Components
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP - Pre-Biased	80 mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50 V	47 kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ lc, Vce:
22 kOhms	60 @ 5mA, 10V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
250mV @ 300μA, 10mA	500nA
Frequency - Transition:	Power - Max:
80 MHz	100 mW
Mounting Type:	Package / Case:
Surface Mount	SOT-723
Supplier Device Package:	Base Product Number:
SSSMini3-F2	UNR31

Environmental & Export classification

Moisture Sensi	tivity Level (MSL):	ECCN:
1 (Unlimited)		EAR99
HTSUS:		
8541.21.0095		

Transistors with built-in Resistor

Panasonic

UNR31AEG

Silicon PNP epitaxial planar type

For digital circuits

Features

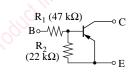
- Suitable for high-density mounting and downsizing of the equipment
- Contribute to low power consumption

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Symbol	Rating	Unit
V _{CBO}	-50	v
V _{CEO}	-50	V
I _C	-80	mA
P _T	100	mW
Tj	125	°C
T _{stg}	-55 to +125	°C
	V _{CBO} V _{CEO} I _C P _T T _j	$\begin{array}{c c} V_{CBO} & -50 \\ \hline V_{CEO} & -50 \\ \hline I_C & -80 \\ \hline P_T & 100 \\ \hline T_j & 125 \\ \hline \end{array}$

- Package
- Code
 SSSMini3-F2
- Marking Symbol: DL
- Pin Name
 - 1: Base
 - 2: Emitter
 - 3: Collector

Internal Connection



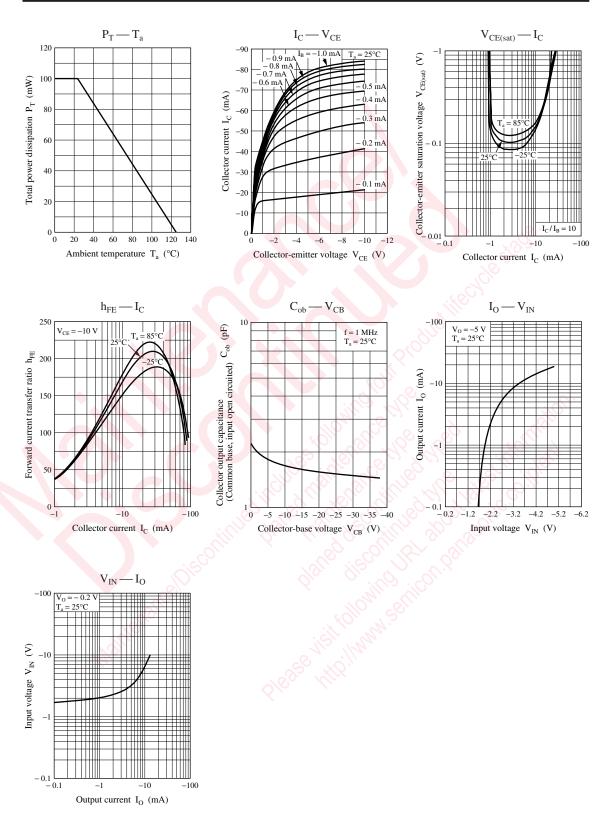
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

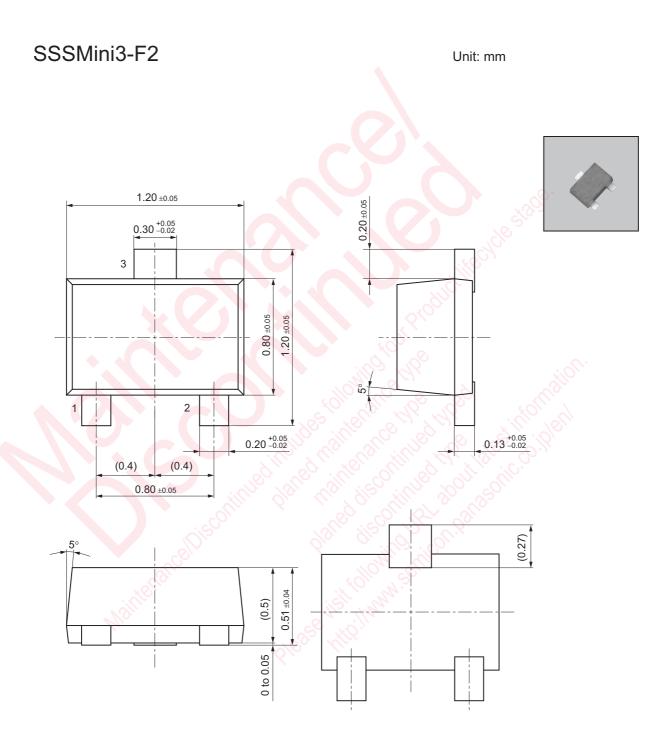
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu A, I_{\rm E} = 0$	-50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Collector-base cut-off current (Emitter open)	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cut-off current (Base open)	I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$			- 0.5	μΑ
Emitter-base cut-off current (Collector open)	I _{EBO}	$V_{EB} = -6 V, I_C = 0$			- 0.2	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$	60			_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -10$ mA, $I_{\rm B} = -0.3$ mA			- 0.25	V
Output voltage high level	V _{OH}	$V_{CC} = -5 \text{ V}, \text{ V}_{B} = -0.5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$	-4.9			V
Output voltage low level	V _{OL}	$V_{CC} = -5 V, V_B = -6 V, R_L = 1 k\Omega$			- 0.2	V
Input resistance	R ₁		-30%	47	+30%	kΩ
Resistance ratio	R ₁ / R ₂		1.7	2.14	2.6	
Transition frequency	f _T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

UNR31AEG







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